arXiv:cond-mat/0206137v2 [cond-mat.str-el] 19 Aug 2002

Direct observation of electron doping in $La_{0.7}Ce_{0.3}MnO_3$ using x-ray absorption spectroscopy

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(Dated: March 22, 2022)

We report on a X-ray absorption spectroscopic (XAS) study on a thin film of $La_{0.7}Ce_{0.3}MnO_3$, a manganite which was previously only speculated to be an electron doped system. The measurements clearly show that the cerium is in the Ce(IV) valence state and that the manganese is present in a mixture of Mn^{2+} and Mn^{3+} valence states. These data unambiguously demonstrate that $La_{0.7}Ce_{0.3}MnO_3$ is an electron doped colossal magnetoresistive manganite, a finding that may open up new opportunities both for device applications as well as for further basic research towards a better modelling of the colossal magnetoresistance phenomenon in these materials.

PACS numbers: 78.70.Dm, 71.28.+d, 72.80.Ga, 75.30.Vn

Hole doped rare-earth manganites of the form $R_{1-x}A_xMnO_3$ (R = rare-earth, A = divalent cation) have been at the focus of attention in recent times in the field of ferromagnetic oxides.[1,2] The interest in these compounds stems from a variety of reasons. These compounds exihibit a large magnetoresistance, coined as 'colossal magnetoresistance' (CMR), close to their ferromagnetic transition temperature (T_c) which makes them potential candidates for device applications. These materials exhibit a strong interplay between spin, charge and orbital degrees of freedom, due to the competition of the various relevant energy scales that are of comparable magnitude. All these give rise to a wide variety of phenomena such as electronic phase separation, charge ordering, spin glass order and half metallicity.[2] It is therefore of prime fundamental interest to study the rich phase diagram of these compounds as a function of doping x and size of the R/A cation.[3]

The basic physics of the hole doped rare-earth manganites can be understood from an interplay of a strong Hund's rule coupling in the manganese and the Jahn-Teller distortion.[4] The divalent cation in these compounds brings the manganese from a Mn^{3+} valence state in the parent compound into a mixture of Mn^{3+} and Mn^{4+}. Double exchange between the Mn^{3+} and the Mn^{4+} cations drives the insulating antiferromagnetic ground state present in the parent compound ($LaMnO_3$) into a ferromagnetic metallic ground state for $x \gtrsim 0.2$ in the doped compound. Above T_c, for compounds such as $La_{0.7}Ca_{0.3}MnO_3$, the decrease in mobility of the electrons due to spin disorder localizes the carriers via the formation of Jahn-Teller polarons. This local deformation around the Jahn-Teller cation Mn^{3+} gives rise to a polaronic insulating state.[5] At temperatures close to T_c, i.e. at the transition between the two phases, an external magnetic field can give rise to CMR. A salient question to ask in this context is: *Can one induce a ferromagnetic metallic ground state by doping electrons instead of holes in the parent compound $LaMnO_3$?* Electron doping is expected to drive the manganese into a mixture of Mn^{2+} and Mn^{3+}. This question is particularly relevant in manganites since manganese can exist in many valence states. In addition, the system has an intrinsic symmetry since Mn^{2+} and Mn^{4+} are both non Jahn-Teller ions whereas Mn^{3+} is a Jahn-Teller ion. Thus, the basic physics in terms of Hund's rule coupling and Jahn-Teller effect could operate in the electron doped phase as well. The existence of an electron doped manganite is not merely of academic interest since it also opens up possibilities for fabricating novel bipolar devices using the electron and hole doped manganites where both spin and charge are utilized.

The crucial issue that we have to address now is *whether it is really possible to electron dope $LaMnO_3$.* One compound, which displays properties remarkably similar to $La_{0.7}Ca_{0.3}MnO_3$, is the cerium doped manganite $La_{0.7}Ce_{0.3}MnO_3$. $La_{0.7}Ce_{0.3}MnO_3$ has a ferromagnetic metallic ground state with $T_c \sim 250$ K.[6,7,8] The ferromagnetic transition is accompanied by a metal-insulator transition and the system has a magnetoresistance ($\rho(0) - \rho(H)/\rho(0)$) in excess of 70% at a field of 1.5 T.[7] It has been shown very recently that a tunnel junction made of the hole doped $La_{0.7}Ca_{0.3}MnO_3$ and $La_{0.7}Ce_{0.3}MnO_3$ exhibits rectifying characteristics[9] in the polaronic insulating state at temperatures $T > T_c$. While this result may suggest that cerium doping drives the manganese in a mixture of Mn^{2+} and Mn^{3+} valencies, there has been so far no direct evidence for electron doping in this compound. One of the main difficulty in this compound is that the system forms in *single phase* only in the epitaxial thin film form,[8] deposited through the energetic pulsed laser ablation process (other methods

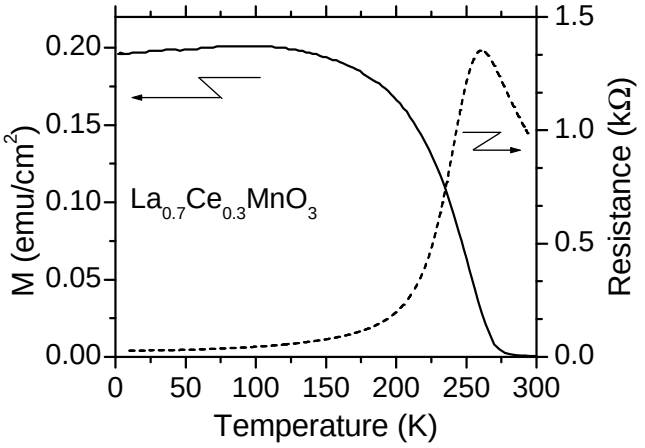


FIG. 1: Temperature dependence of the magnetization (full line, left scale) and resistance (dashed line, right scale) of the investigated $La_{0.7}Ce_{0.3}MnO_3$ thin film sample. The magnetization measurement was conducted in an applied field of 1 kOe.

failed in this respect[10]). This precludes the possibility of using conventional techniques such as chemical analysis. In addition, it is *a priori* not obvious that cerium has enough reducing power to drive Mn^{3+} towards the electro positive Mn^{2+}, in view of the observation that formally tetravalent CeO_2 has an extremely large amount of oxygen holes.[11]

In this paper we provide a direct evidence of the Ce and Mn valence states in $La_{0.7}Ce_{0.3}MnO_3$ through X-ray absorption measurements on epitaxial thin films of these compounds.

Bulk polycrystalline targets of $La_{0.7}Ce_{0.3}MnO_3$ and $LaMnO_3$ were prepared by a solid state reaction route as reported earlier.[8] Using these targets, epitaxial films were deposited by pulsed laser deposition (PLD) on $SrTiO_3$ (STO) substrate, using a KrF excimer laser. The substrate temperature was kept between 790^{o}C and 800^{o}C at all times. The laser energy density was approximately 3 J/cm^2 with a repetition rate of 9 Hz and the laser wavelength was 248 nm. The $La_{0.7}Ce_{0.3}MnO_3$ film was grown at an oxygen pressure of 400 mTorr whereas the $LaMnO_3$ film was deposited at 100 mTorr. The lower oxygen pressure during growth of the $LaMnO_3$ film was necessary to avoid over-oxygenation which can induce considerable hole doping in this compound. After deposition, the laser ablation chamber was vented with high purity oxygen and the substrate cooled down to room temperature. Details of the x-ray characterization can be found in Ref. 8. Several reflections were taken in the x-ray analysis to ascertain the single phase nature of the films.

Magnetization was measured using a Quantum Design superconducting quantum interference device (SQUID). The $LaMnO_3$ had a weak ferromagnetic transition around 115 K. This weak ferromagnetism could be due to a slight oxygen non-stoichiometry in the film as has been observed before in bulk samples.[12] Also, a weak ferromagnetic moment in the A-type antiferromagnet $LaMnO_3$ is believed to arise from the Dzyaloshinsky-Moryia interaction.[2] The temperature dependence of the magnetization for the film of interest, $La_{0.7}Ce_{0.3}MnO_3$, is shown in Fig. 1. A $T_c \approx 260$ K can be inferred. From the magnetization data there is no sign of any magnetic impurity phase in our sample. In addition, the hallmark of the CMR material is depicted in Fig. 1: a maximum of the resistance in dependence on temperature near T_C. There is a similarity in the magnetic properties of $La_{0.7}Ce_{0.3}MnO_3$ and its hole doped analogue $La_{0.7}Ca_{0.3}MnO_3$ in the sense that both have similar Curie temperatures. It is known that perovskite rare-earth manganites such as $LaMnO_3$ can accept a large excess of oxygen via the formation of cation vacancies inducing hole doping in the parent compound.[12] Therefore, to confirm that the system $La_{0.7}Ce_{0.3}MnO_3$ is indeed electron doped and the magnetic ordering does not occur due to the existence of Mn^{4+} and Mn^{3+} valence states resulting from over-oxygenation of the film one must study both the Ce as well as the Mn valence states.

The Ce-$M_{4,5}$ and Mn-$L_{2,3}$ XAS measurements were performed using the Dragon beamline at the Synchrotron Radiation Research Center (SRRC) in Taiwan. The experimental photon energy resolution was approx. 0.2 and 0.3 eV at the Mn-$L_{2,3}$ and Ce-$M_{4,5}$ thresholds, respectively. The spectra were recorded at room temperature, employing the total electron-yield method by measuring the sample drain current to ground. In addition, the incident beam flux was monitored simultaneously with a gold mesh in the beam line which allowed the obtained spectra to be normalized very accurately.

It is well known that the x-ray absorption spectra at the rare-earth $M_{4,5}$ and the 3d transition metal $L_{2,3}$ thresholds are highly sensitive to the valence state and the distribution of valence electrons between the metal ion and the ligand orbitals since the experimental spectral structures can be well reproduced by atomic multiplet calculations.[13,14,15,16,17] Fig. 2 shows the Ce-$M_{4,5}$ XAS spectrum of $La_{0.7}Ce_{0.3}MnO_3$. For comparison, the spectra of the reference materials CeO_2 and CeF_3 are also included. The Ce-$M_{4,5}$ XAS spectrum of the formally tetravalent Ce-compound CeO_2 consists of a single main structure (M) at 887 eV and a satellite (S) at $\cong$ 6 eV above the main peak. The tetravalence of the Ce in $La_{0.7}Ce_{0.3}MnO_3$ can be easily recognized since the spectral features are very similar to those of CeO_2. In tetravalent compounds like CeO_2, the Ce–4f and O–2p covalence can be described[14] in a configuration interaction scheme, in which the ground state is given by $|g\rangle = \alpha\,|\,4f^0\rangle + \beta\,|\,4f^1\underline{L}\rangle$ ($\underline{L}$ refers to the ligand hole) while the final states can be labelled as the bonding and anti-bonding states of $3d^9 4f^1$ and $3d^9 4f^2\underline{L}$. These two final states give rise to the main peak and the higher energy satellite. By an interference effect[14] the intensity of the anti-bonding state is strongly reduced, especially if the charge transfer energy between the two configurations

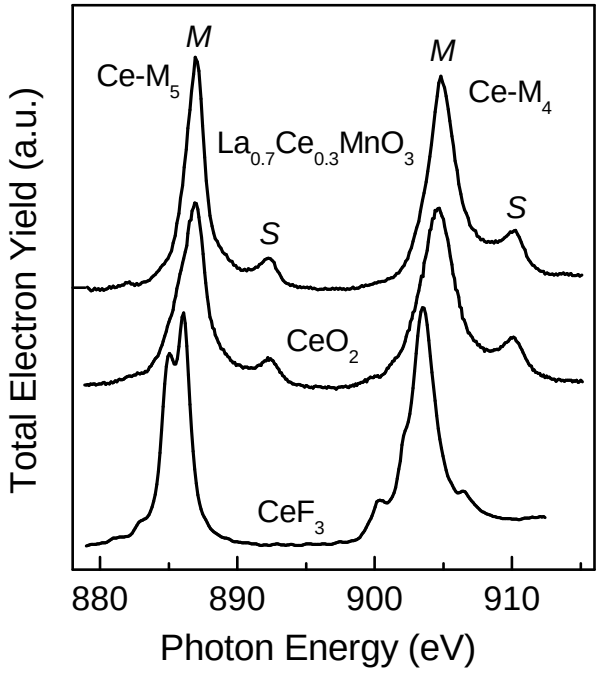


FIG. 2: Ce-$M_{4,5}$ XAS spectra of $La_{0.7}Ce_{0.3}MnO_3$ and of CeO_2 for a tetravalent and CeF_3 for a trivalent reference.

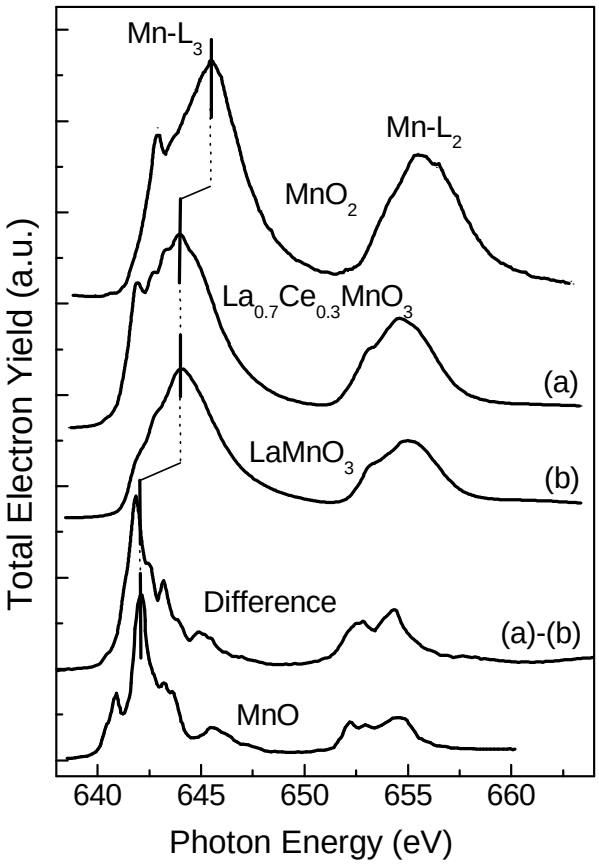


FIG. 3: Mn-$L_{2,3}$ XAS spectra of $La_{0.7}Ce_{0.3}MnO_3$ (a) and for comparison of MnO_2, $LaMnO_3$ (b) and MnO for Mn^{4+}, Mn^{3+} and Mn^{2+} references, respectively. The curve labeled "difference" ((a)-(b)) is the difference between the $La_{0.7}Ce_{0.3}MnO_3$ and the $LaMnO_3$ spectra. In comparison to the MnO spectrum, this difference curve clearly indicates the existence of Mn^{2+} in $La_{0.7}Ce_{0.3}MnO_3$.

in the ground state and the final state is nearly the same. Therefore, the higher energy anti-bonding state appears usually as a weak satellite. Nevertheless, the presence of such a weak satellite indicates that the $4f$ occupancy is about 0.5, as a careful theoretical analysis has shown.[14]

In contrast to the single-peaked structure in Ce(IV)-compounds, the main spectral features of the trivalent Ce-compound CeF_3 exhibits a more complicated multiplet structure which could be very well reproduced by atomic multiplet calculations.[13] It is well known[18] that the $M_{4,5}$ spectrum of trivalent rare-earth elements is shifted to lower energy by more than 1 eV with a decrease in their valence. Here, we observe a shift of $\cong 1.5$ eV towards lower energy in the CeF_3 spectrum with respect to the spectra of CeO_2 and $La_{0.7}Ce_{0.3}MnO_3$. Therefore, the Ce-$M_{4,5}$ spectrum of Ce(IV)-compounds is very sensitive to trivalent impurities. One can see that even CeO_2 has some very small Ce^{3+} content as suggested by the small asymmetry in the two peaks near the low energy side. The main peaks of the Ce $M_{4,5}$-edge in $La_{0.7}Ce_{0.3}MnO_3$, however, are perfectly symmetric, indicating a pure Ce(IV) valence state of Ce in this compound.

The existence of Ce(IV), however, still does not confirm that the sample is electron doped. In the past it has been shown that in a bulk polycrystalline sample some amount of CeO_2 remains unreacted though the epitaxial thin film of $La_{0.7}Ce_{0.3}MnO_3$ forms in single phase.[8] Thus, to conclusively establish that it is indeed an electron doped system one has to search for a corresponding replacement of Mn^{3+} by Mn^{2+} as well. We have measured the Mn-$L_{2,3}$ XAS spectra to investigate the valence state of Mn in the ground state. Fig. 3 shows the Mn-$L_{2,3}$ spectra of $La_{0.7}Ce_{0.3}MnO_3$ and—for comparison—of MnO_2, $LaMnO_3$ and MnO for Mn^{4+}, Mn^{3+} and Mn^{2+} references, respectively. The $LaMnO_3$ spectrum is similar to that obtained previously.[19,20] It is a well known fact[21,22,23] that an increase of the metal ion valence by one results in shift of the $L_{2,3}$ XAS spectra to higher energy by about 1 eV or more. In Fig. 3 we can see a shift towards higher energy from bottom to top in a sequence of increasing Mn valence from Mn^{2+} (MnO) to Mn^{3+} ($LaMnO_3$) and further to Mn^{4+} (MnO_2). In comparison to undoped $LaMnO_3$, in $La_{0.7}Ce_{0.3}MnO_3$ we can see new and sharp low energy structures at nearly the same energy position as in the MnO spectrum. These sharp structures at around 642 eV are a reliable benchmark of the appearance of a divalent Mn state since they are hardly smeared by background or other structures. The observed spectral features indicate the existence of a Mn^{2+} component in addition to Mn^{3+} in the single phase $La_{0.7}Ce_{0.3}MnO_3$ compound. In order to estimate the Mn^{2+} content, the *normalized* spectrum of $LaMnO_3$

has been substracted from that of $La_{0.7}Ce_{0.3}MnO_3$ (the resultant difference spectrum is labeled "difference" in Fig. 3). The most reasonable difference spectrum was obtained if the spectral weight of the substracted $LaMnO_3$ spectrum was taken as 82%. The main structures of the difference spectrum are found at the same energy position as the prominent features of the MnO spectrum (as indicated by the vertical line in Fig. 3) and the overall appearance of the difference and the MnO spectra is very similar. However, the difference spectrum in its details is not exactly the same as that of MnO. As an example, there is a sharp shoulder (at around 641 eV) below the main peak found in MnO which is nearly absent in the difference spectrum. Such subtle distinctions are to be expected because of the difference in the local symmetry of Mn in these two compounds. In fact, there is an additional feature just above the main peak in the L_3-edge of the difference spectrum and the main peak is further shifted to lower energy by 0.2 eV. Also, a change at the Mn L_2-edge is clearly seen.

In order to estimate the contents of Mn^{2+} and Mn^{3+} from the corresponding spectral weights (18% and 82%, respectively) one needs to bear in mind that, formally, Mn^{2+} has 5 holes in the 3d-orbital whereas Mn^{3+} has 6 holes. Assuming completely ionic Mn^{2+} and Mn^{3+}, the content of Mn^{2+} is about 20%. However, the strong covalence of Mn^{3+} may reduce this number slightly. Even though the latter effect is difficult to account for the main error originates from the uncertainty in determining the spectral weight of Mn^{2+} and hence, we estimate the Mn^{2+}-content in $La_{0.7}Ce_{0.3}MnO_3$ to $20(\pm 4)\%$. The deviation from the nominal 30% Ce doping may be due to the fact that the system might have been over-oxygenated which gives rise to an excess of Mn^{3+}-content.

In summary, we have shown from XAS measurements that $La_{0.7}Ce_{0.3}MnO_3$ is an electron doped manganite where the formally tetravalent cerium drives the manganese into a mixture of Mn^{2+} and Mn^{3+} valence states. Thus, it is tempting to think that the ferromagnetism in this compound is brought about by the double exchange between Mn^{2+}/Mn^{3+} ions. The remarkable similarity between this compound and its hole doped counterpart, $La_{0.7}Ca_{0.3}MnO_3$, provides further motivation to explore the electron doped phase in detail. One issue of particular interest is the spin state of manganese in $La_{0.7}Ce_{0.3}MnO_3$. Recent observation of a large positive magnetoresistance in ferromagnetic tunnel junctions involving $La_{0.7}Ce_{0.3}MnO_3$ and a hole doped manganite as the ferromagnetic electrodes suggests that the manganese in this compound may be in an intermediate spin state.[24] This would significantly modify our understanding of the origin of CMR in this compound in terms of on-site Hund's rule coupling. We hope that this work will motivate further studies on the electron doped phase of rare-earth manganites.

The authors would like to acknowledge Peter Oppeneer, F. Steglich, Andy Mackenzie, S. K. Dhar and R. Pinto for helpful discussions and encouragement. We would also like to thank Chris Muirhead, Radoslav Chakalov and Peter Mann for experimental help. P.R. wishes to thank the Leverhulme Trust for financial support. The research of Z.H. and L.H.T. is supported by the Deutsche Forschungsgemeinschaft through SFB 608.

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